

## KVR16S11K2/16

16GB (8GB 2Rx8 1G x 64-Bit x 2 pcs.)  
PC3-12800 CL11 204-Pin SODIMM Kit

### DESCRIPTION

ValueRAM's KVR16S11K2/16 is a kit of two 1G x 64-bit (8GB) DDR3-1600 CL11 SDRAM (Synchronous DRAM) 2Rx8, memory modules, based on sixteen 512M x 8-bit FBGA components per module. Total kit capacity is 16GB. The SPDs are programmed to JEDEC standard latency DDR3-1600 timing of 11-11-11 at 1.5V. Each 204-pin SODIMM uses gold contact fingers. The electrical and mechanical specifications are as follows:

### FEATURES

- JEDEC standard 1.5V (1.425V ~1.575V) Power Supply
- VDDQ = 1.5V (1.425V ~ 1.575V)
- 800MHz fCK for 1600Mb/sec/pin
- 8 independent internal bank
- Programmable CAS Latency: 11, 10, 9, 8, 7, 6
- Programmable Additive Latency: 0, CL - 2, or CL - 1 clock
- 8-bit pre-fetch
- Burst Length: 8 (Interleave without any limit, sequential with starting address "000" only), 4 with tCCD = 4 which does not allow seamless read or write [either on the fly using A12 or MRS]
- Bi-directional Differential Data Strobe
- Internal(self) calibration : Internal self calibration through ZQ pin (RZQ : 240 ohm ± 1%)
- On Die Termination using ODT pin
- Average Refresh Period 7.8us at lower than TCASE 85°C, 3.9us at 85°C < TCASE ≤ 95°C
- Asynchronous Reset
- PCB : Height 1.180" (30.00mm), double sided component

### SPECIFICATIONS

|  |                       |
|--|-----------------------|
| CL(IDD)  | 11 cycles             |
| Row Cycle Time (tRCmin)                          | 48.125ns (min.)       |
| Refresh to Active/Refresh Command Time (tRFCmin) | 260ns (min.)          |
| Row Active Time (tRASmin)                        | 35ns (min.)           |
| Maximum Operating Power                          | 2.580 W* (per module) |
| UL Rating  | 94 V - 0              |
| Operating Temperature                            | 0° C to 85° C         |
| Storage Temperature                              | -55° C to +100° C     |

\*Power will vary depending on the SDRAM used.

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### MODULE DIMENSIONS:

